Soft-Start Controlled Load Switch with Auto Discharge

The NCP331 is a low Ron N-channel MOSFET controlled by a soft-start sequence of 2 ms for mobile applications. The very low $R_{DS(on)}$ allows system supplying or battery charging up to DC 2A. The device is enable due to external, active high, enable pin.

Due to a current consumption optimization, leakage current is drastically decreased from the battery connected to the device, allowing long battery life.

Features

- 1.8 V 5.5 V Operating Range
- 33 mΩ N MOSFET
- DC Current Up to 2 A
- Peak Current Up to 5 A
- Built-in Soft-Start 2 ms
- Reverse Voltage Protection
- Output Discharge
- EN Logic Pin: Active High
- ESD Ratings: Machine Model = B Human Body Model = 2
- TSOP23-6 package
- This is a Pb-Free Device

Typical Applications

- Mobile Phones
- Tablets
- Digital Cameras
- GPS
- Computers

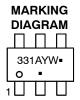


ON Semiconductor®

http://onsemi.com



TSOP-6 SN SUFFIX CASE 318G

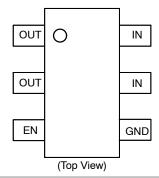


331 = Specific Device Code A = Assembly Location

Y = Year
W = Work Week
Pb-Free Package

(Note: Microdot may be in either location)

PINOUT DIAGRAM



ORDERING INFORMATION

See detailed ordering and shipping information on page 7 of this data sheet.

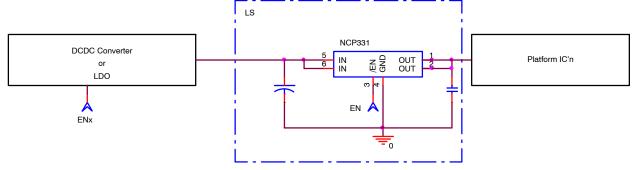
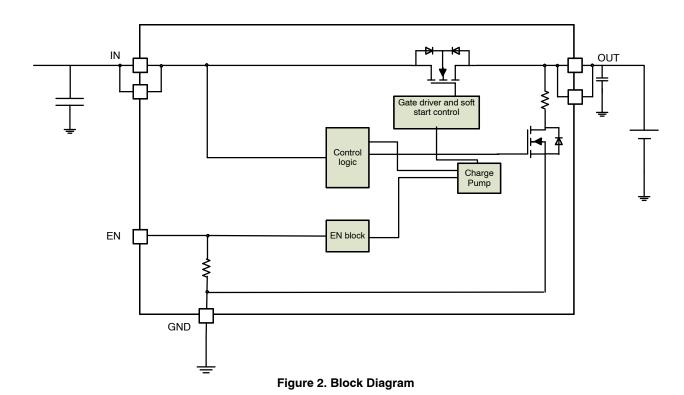


Figure 1. Typical Application Circuit

PIN FUNCTION DESCRIPTION

Pin Name	Pin Number	Type	Description	
IN	5,6	POWER	Power–switch input voltage; connect a 0.1 μF or greater ceramic capacitor from IN to GND as close as possible to the IC.	
GND	4	POWER	Ground connection.	
EN	3	INPUT	Enable input, logic high turns on power switch.	
OUT	1,2	OUTPUT	Power–switch output; connect a 0.1 μF ceramic capacitor from OUT to GND as clospossible to the IC is recommended.	

BLOCK DIAGRAM



http://onsemi.com

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
IN, OUT, EN, Pins:	V _{EN,} V _{IN,} V _{OUT}	-0.3 to +7.0	V
From IN to OUT Pins: Input/Output	$V_{IN,}V_{OUT}$	-7.0 to +7.0	V
Maximum Junction Temperature Range	TJ	-40 to +125	°C
Storage Temperature Range	T _{STG}	-40 to +150	°C
ESD Withstand Voltage Human Body model (HBM), model = 2, Machine Model (MM) model = B, (Note 1)	Vesd	2500 200	V
Moisture Sensitivity (Note 2)	MSL	Level 1	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. According to JEDEC standard JESD22–A108.

2. Moisture Sensitivity Level (MSL): 1 per IPC/JEDEC standard: J–STD–020.

OPERATING CONDITIONS

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{IN}	Operational Power Supply		1.8		5.5	V
V _{EN}	Enable Voltage		0		5.5	
T _A	Ambient Temperature Range		-40	25	+ 85	°C
T_J	Junction Temperature Range		-40	25	+ 125	°C
C _{IN}	Decoupling Input Capacitor		0.1			μF
C _{OUT}	Decoupling Output Capacitor		0.1			μF
$R_{\theta JA}$	Thermal Resistance – Junction-to-Air	(Notes 3 and 4)		305		°C/W
lout	Maximum DC Current				2	Α
P _D	Power Dissipation Rating (Note 7)	T _A ≤ 25°C		0.37		W
		T _A = 85°C		0.13		W

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

3. The R_{θJA} is dependent of the PCB heat dissipation.

- 4. The maximum power dissipation (P_{D}) is given by the following formula:

ELECTRICAL CHARACTERISTICS Min & Max Limits apply for T_A between -40°C to +85°C and T_J up to + 125°C for V_{IN} between 1.8 V to 5.5 V (Unless otherwise noted). Typical values are referenced to T_A = + 25°C and V_{IN} = 5 V.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit	
POWER S	WITCH							
	Static drain-source on-state resistance	V _{IN} = 3 V, V _{IN} = 5 V, TSOP package	T _J = 25°C		33		mΩ	
			–40°C < T _J < 125°C			60		
T _{EN} Gate turi	Gate turn on	V _{IN} = 3.3 V	From EN Vih to V _{OUT} rising. (Note 5), C _{LOAD} = 0.1 μ F, R _{LOAD} = 10 Ω		60	200	μs	
	Salo lan on	V _{IN} = 3.0 V	From EN Vih to 10% V_{OUT} rising. C_{LOAD} = 1 μ F, R_{LOAD} = 25 Ω		278	500	μs	
	Output sing time	V _{IN} = 3.3 V	C_{LOAD} = 0.1 μ F, R_{LOAD} = 10 Ω (Note 5), from En to 95% V_{OUT}	1.2	2.05	3		
T _R	Output rise time	V _{IN} = 3.0 V	C_{LOAD} = 1 μF, R_{LOAD} = 25 Ω (Note 6), from 10% to 90% V_{OUT}	1.00	1.65	2.36		
Tdis	Disable time	V _{IN} = 3.0 V	From EN high to low to V _{OUT} falling		0.3		ms	
T _F	Output fall time	V _{IN} = 3 V	C_{LOAD} = 1 μ F, R_{LOAD} = 25 Ω (Note 6)	0.1	0.18	0.5		
T _{OFF}	Output off time	V _{IN} = 3 V	C_{LOAD} = 1 μ F, R_{LOAD} = 25 Ω (Notes 6 & 7), from EN to 10% V_{OUT}	0.3	0.5	0.8		
ENABLE I	NPUT EN		•			•	•	
V _{IH}	High-level input voltage			1.15			V	
V _{IL}	Low-level input voltage					0.85	V	
R _{pd}	En pull-down resistor			1.1	1.5	1.8	МΩ	
R _{dis}	Output discharge resistor			200	400	600	Ω	
REVERSE	-LEAKAGE PROTECTION							
I_{REV} Reverse-current $V_{IN} = 0 \text{ V}, V_{OUT} = 4.2 \text{ V} \text{ (part disable)}, T_A = 25^{\circ}\text{C}$				0.3	1.2	μА		
QUIESCE	NT CURRENT							
Istb	Standby current	En low, Vin = 3 V			1.3	3	μΑ	
Iq	Current consumption	No load, En high, Vin = 3 V			11	15	μΑ	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

Guaranteed by correlation with 3.0 V production test.
 Parameters are guaranteed for C_{LOAD} and R_{LOAD} connected to the OUT pin with respect to the ground.
 Guaranteed by T_{fall} and R_{discharge} tests.

TIMINGS

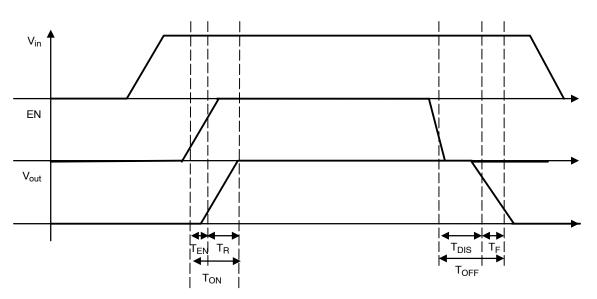
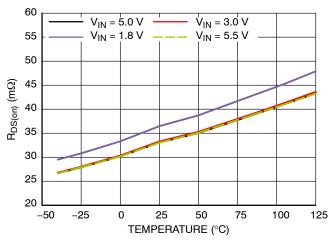


Figure 3. Timings

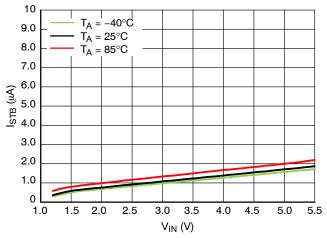
TYPICAL CHARACTERISTICS



50 45 40 $R_{DS(on)}$ (m Ω) 35 30 25 20 1.5 2 2.5 3 3.5 4 4.5 5.5 $V_{IN}(V)$

Figure 4. R_{DS(on)} versus Temperature

Figure 5. R_{DS(on)} versus Input Voltage, Ambient Temperature



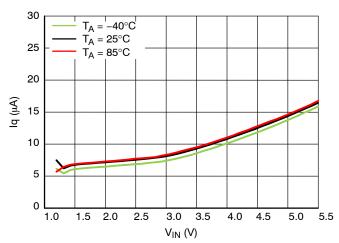


Figure 6. Standby Current versus Input Voltage

Figure 7. Quiescent Current versus Input Voltage

FUNCTIONAL DESCRIPTION

Overview

The NCP331 is a high side N channel MOSFET power distribution switch designed to connect external voltage directly to the system.

Enable Input

Enable pin is an active high.

The part is in disable mode when EN is tied to low. Power MOSFET is opened. Pull down resistor is placed to maintained the part off if En pin is not externally driven.

The parts becomes in enable mode if EN is tied high and Power MOSFET is turned of after ten and t_{rise} times.

Auto Discharge

NMOS FET is placed between the output pin and GND, in order to discharge the application capacitor connected on OUT pin.

The auto-discharge is activated when EN pin is set to low level (disable state).

The discharge path (Pull down NMOS) stays activated as long as EN pin is set at low level.

Blocking Control

The blocking control circuitry switches the bulk of the power NMOS. When the part is off (No V_{in} or EN tied to GND externally), the body diode limits the leakage current I_{REV} from OUT to IN. In this mode, anode of the body diode is connected to IN pin and cathode is connected to OUT pin. In operating condition, anode of the body diode is connected to OUT pin and cathode is connected to IN pin preventing the discharge of the power supply.

APPLICATION INFORMATION

Power Dissipation

The device's junction temperature depends on different contributor factor such as board layout, ambient temperature, device environment, etc... Yet, the main contributor in term of junction temperature is the power dissipation of the power MOSFET. Assuming this, the power dissipation and the junction temperature in normal mode can be calculated with the following equations:

$$P_D = R_{DS(on)} \times (I_{OUT})^2$$

P_D = Power dissipation (W)

 $R_{DS(on)}$ = Power MOSFET on resistance (Ω)

 I_{OUT} = Output current (A)

$T_{J} = P_{D} \times R_{\theta,JA} + T_{A}$

 T_J = Junction temperature (°C)

 $R_{\theta JA}$ = Package thermal resistance (°C/W)

 T_A = Ambient temperature (°C)

PCB Recommendations

The NCP331 integrates an up to 2A rated NMOS FET, and the PCB design rules must be respected to properly evacuate the heat out of the silicon. By increasing PCB area, the $R_{\theta JA}$ of the package can be decreased, allowing higher power dissipation.

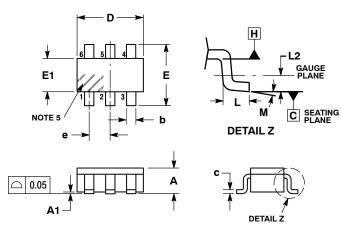
ORDERING INFORMATION

Device	Marking	Package	Shipping [†]
NCP331SNT1G	331	TSOP-6 (Pb-Free)	3000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PACKAGE DIMENSIONS

TSOP-6 CASE 318G-02 ISSUE V

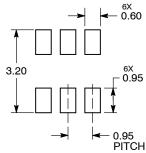


- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 CONTROLLING DIMENSION: MILLIMETERS.

- CONTROLLING DIMENSION: MILLIMETERS.
 MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
 DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.15 PER SIDE. DIMENSIONS D AND E1 ARE DETERMINED AT DATUM H.
 PIN ONE INDICATOR MUST BE LOCATED IN THE INDICATED ZONE.

	MILLIMETERS				
DIM	MIN	MAX			
Α	0.90	1.00	1.10		
A1	0.01	0.06	0.10		
b	0.25	0.38	0.50		
С	0.10	0.18	0.26		
D	2.90	3.00	3.10		
E	2.50	2.75	3.00		
E1	1.30	1.50	1.70		
е	0.85	0.95	1.05		
L	0.20	0.40	0.60		
L2	0.25 BSC				
М	0°	_	10°		

RECOMMENDED SOLDERING FOOTPRINT*



DIMENSIONS: MILLIMETERS

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ON Semiconductor and (III) are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of SCILLC's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any reserves the right to make dranges without further holice to any products herein. Scilled makes no warrany, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specificatly disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all Claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor P.O. Box 5163, Denver, Colorado 80217 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com

N. American Technical Support: 800-282-9855 Toll Free Europe, Middle East and Africa Technical Support:

Phone: 421 33 790 2910 Japan Customer Focus Center Phone: 81-3-5817-1050

ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

ON Semiconductor: NCP331SNT1G